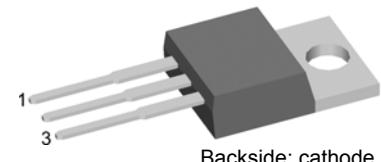
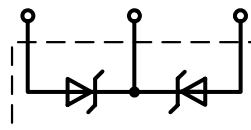


tentative

**Schottky**

High Performance Schottky Diode  
 Low Loss and Soft Recovery  
 Common Cathode

 **$V_{RRM} = 60\text{ V}$**  **$I_{FAV} = 2 \times 15\text{ A}$**  **$V_F = 0.68\text{ V}$** **Part number****DSA 30 C 60PB**

Backside: cathode

**Features / Advantages:**

- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{rm}$ -values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package:**

TO-220AB

- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

| Ratings    |                                       |   |                                      |      |      |
|------------|---------------------------------------|---|--------------------------------------|------|------|
| Symbol     | Definition                            | Conditions  | min.                                 | typ. | max. |
| $V_{RRM}$  | max. repetitive reverse voltage       | $T_{VJ} = 25\text{ }^\circ\text{C}$               |                                      |      | 60   |
| $I_R$      | reverse current                       | $V_R = 60\text{ V}$                               |                                      |      | 0.5  |
|            |                                       | $V_R = 60\text{ V}$                               |                                      |      | 5    |
| $V_F$      | forward voltage                       | $I_F = 15\text{ A}$                               | $T_{VJ} = 25\text{ }^\circ\text{C}$  |      | 0.85 |
|            |                                       | $I_F = 30\text{ A}$                               |                                      |      | 0.95 |
|            |                                       | $I_F = 15\text{ A}$                               | $T_{VJ} = 125\text{ }^\circ\text{C}$ |      | 0.68 |
|            |                                       | $I_F = 30\text{ A}$                               |                                      |      | 0.78 |
| $I_{FAV}$  | average forward current               | rectangular, $d = 0.5$                            | $T_c = 150\text{ }^\circ\text{C}$    |      | 15   |
| $r_F$      | threshold voltage<br>slope resistance | for power loss calculation only                   | $T_{VJ} = 175\text{ }^\circ\text{C}$ |      | 0.44 |
|            |                                       |   |                                      |      | 11.2 |
| $R_{thJC}$ | thermal resistance junction to case   |   |                                      |      | 1.75 |
| $T_{VJ}$   | virtual junction temperature          |   | -55                                  |      | 175  |
| $P_{tot}$  | total power dissipation               |   |                                      |      | 85   |
| $I_{FSM}$  | max. forward surge current            | $t_p = 10\text{ ms (50 Hz), sine}$                | $T_{VJ} = 45\text{ }^\circ\text{C}$  |      | 130  |
| $C_J$      | junction capacitance                  | $V_R = \text{tbd V}; f = 1\text{ MHz}$            | $T_{VJ} = 25\text{ }^\circ\text{C}$  | tbd  | pF   |
| $E_{AS}$   | non-repetitive avalanche energy       | $I_{AS} = 1\text{ A}; L = 100\text{ }\mu\text{H}$ | $T_{VJ} = 25\text{ }^\circ\text{C}$  |      | 0.05 |
| $I_{AR}$   | repetitive avalanche current          | $V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$   |                                      |      | 0.1  |

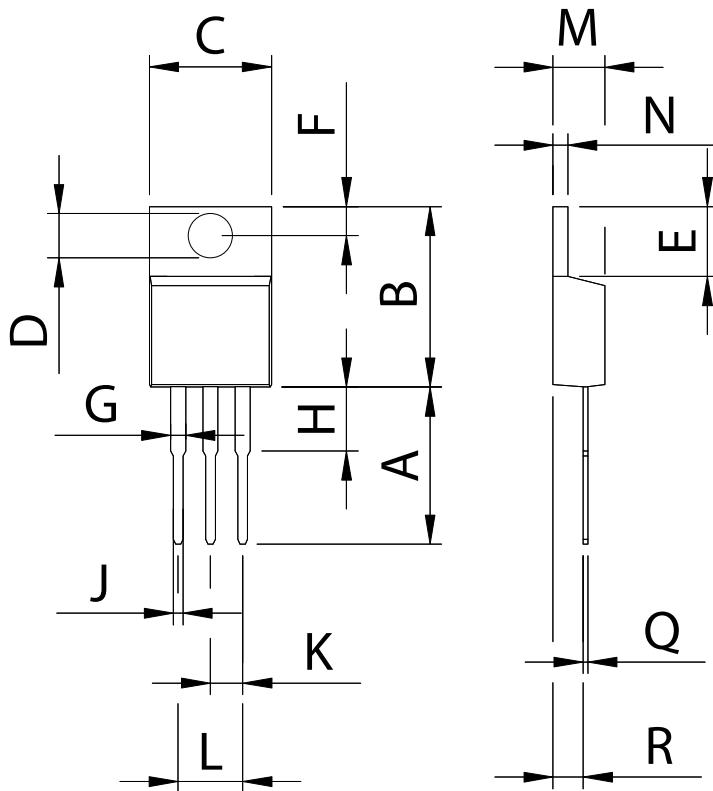
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| Symbol     | Definition                          | Conditions | Ratings |      |      |     |
|------------|-------------------------------------|------------|---------|------|------|-----|
|            |                                     |            | min.    | typ. | max. |     |
| $I_{RMS}$  | RMS current                         | per pin*   |         |      | 35   | A   |
| $R_{thCH}$ | thermal resistance case to heatsink |            |         | 0.50 |      | K/W |
| $M_D$      | mounting torque                     |            | 0.4     |      | 0.6  | Nm  |
| $F_C$      | mounting force with clip            |            | 20      |      | 60   | N   |
| $T_{stg}$  | storage temperature                 |            | -55     |      | 150  | °C  |
| Weight     |                                     |            |         | 2    |      | g   |

\*  $I_{RMS}$  is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

### Outlines TO-220AB



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 12.70      | 13.97 | 0.500  | 0.550 |
| B    | 14.73      | 16.00 | 0.580  | 0.630 |
| C    | 9.91       | 10.66 | 0.390  | 0.420 |
| D    | 3.54       | 4.08  | 0.139  | 0.161 |
| E    | 5.85       | 6.85  | 0.230  | 0.270 |
| F    | 2.54       | 3.18  | 0.100  | 0.125 |
| G    | 1.15       | 1.65  | 0.045  | 0.065 |
| H    | 2.79       | 5.84  | 0.110  | 0.230 |
| J    | 0.64       | 1.01  | 0.025  | 0.040 |
| K    | 2.54       | BSC   | 0.100  | BSC   |
| M    | 4.32       | 4.82  | 0.170  | 0.190 |
| N    | 1.14       | 1.39  | 0.045  | 0.055 |
| Q    | 0.35       | 0.56  | 0.014  | 0.022 |
| R    | 2.29       | 2.79  | 0.090  | 0.110 |